

BUL381D

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- LOW SPREAD OF DYNAMIC PARAMETERS
- MINIMUM LOT-TO-LOT SPREAD FOR RELIABLE OPERATION
- VERY HIGH SWITCHING SPEED
- LARGE RBSOA
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

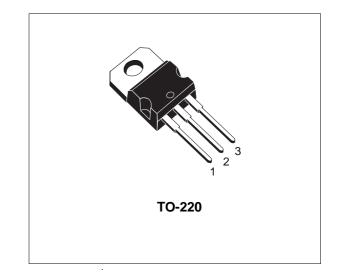
APPLICATIONS

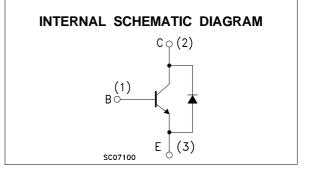
- ELECTRONIC TRANSFORMERS FOR HALOGEN LAMPS
- ELECTRONIC BALLASTS FOR
 FLUORESCENT LIGHTING
- SWITCH MODE POWER SUPPLIES

DESCRIPTION

The BUL381D is manufactured using high voltage Multi Epitaxial Planar technology for high switching speeds and high voltage capability.

The BUL series is designed for use in lighting applications and low cost switch-mode power supplies.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		
VCES	Collector-Emitter Voltage (V _{BE} = 0)	800	V	
Vceo	Collector-Emitter Voltage $(I_B = 0)$	400	V	
V _{EBO}	Emitter-Base Voltage (I _C = 0)	9	V	
lc	Collector Current	5	А	
Ісм	Collector Peak Current (t _p < 5 ms)	8	А	
IB	Base Current	2	А	
I _{BM}	Base Peak Current (t _p < 5 ms)	4	А	
P _{tot}	Total Dissipation at $T_c = 25$ °C	70	W	
T _{stg}	Storage Temperature	-65 to 150	°C	
Tj	Max. Operating Junction Temperature	150	°C	

THERMAL DATA

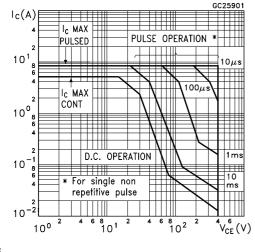
R _{thj-case}	Thermal Resistance Junction-Case	Max	1.78	°C/W
R _{thj-amb}	Thermal Resistance Junction-Ambient	Max	62.5	°C/W

ELECTRICAL CHARACTERISTICS ($T_{case} = 25 \ ^{\circ}C$ unless otherwise specified)

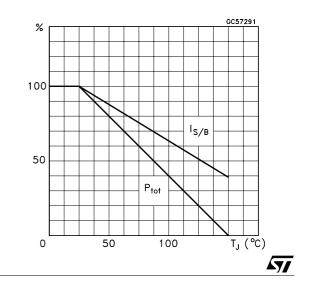
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	$V_{CE} = 800 V$ $V_{CE} = 800 V$ $T_j = 125 \ ^{o}C$			100 500	μΑ μΑ
ICEO	Collector Cut-off Current ($I_B = 0$)	V _{CE} = 400 V			250	μA
$V_{CEO(sus)^*}$	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100 mA L = 25 mH				V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	I _E = 10 mA	9			V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$ \begin{array}{ll} I_{C} = 1 \ A & I_{B} = 0.2 \ A \\ I_{C} = 2 \ A & I_{B} = 0.4 \ A \\ I_{C} = 3 \ A & I_{B} = 0.75 \ A \end{array} $			0.5 0.7 1.1	V V V
V _{BE(sat)} *	Base-Emitter Saturation Voltage				1.1 1.2	V V
h _{FE} *	DC Current Gain		8 10			
t _s t _f	RESISTIVE LOAD Storage Time Fall Time		1.5		2.5 0.8	μs μs
t _s t _f	INDUCTIVE LOAD Storage Time Fall Time			1.3 100		μs ns
Vf	Diode Forward Voltage	$I_{C} = 2 A$			2.5	V

* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

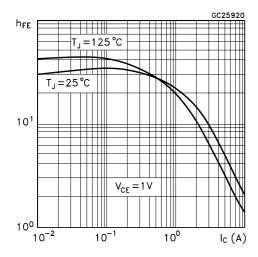
Safe Operating Area



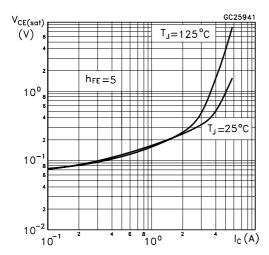
Derating Curve



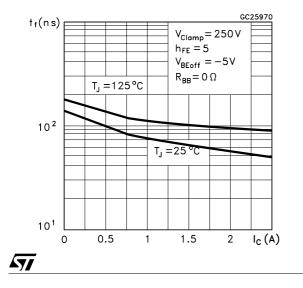
DC Current Gain



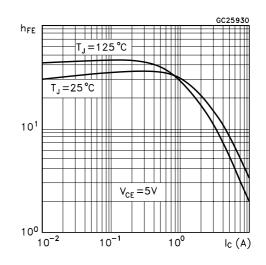
Collector Emitter Saturation Voltage



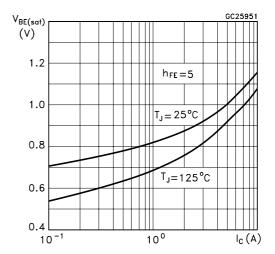
Inductive Fall Time



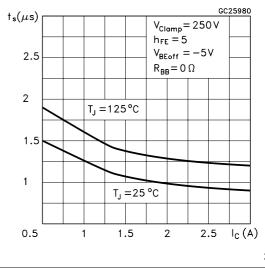
DC Current Gain



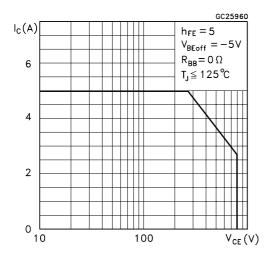
Base Emitter Saturation Voltage



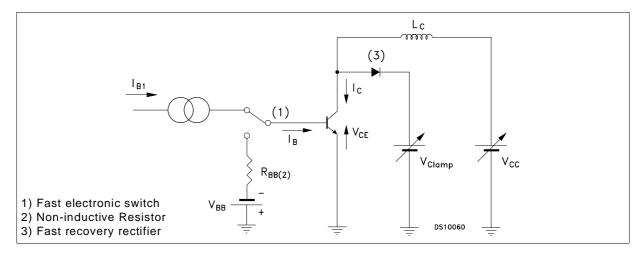




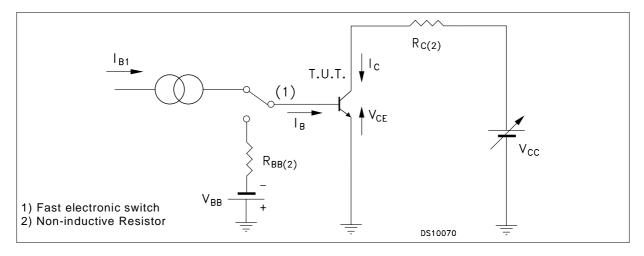
Reverse Biased SOA



Inductive Load Switching Test Circuit



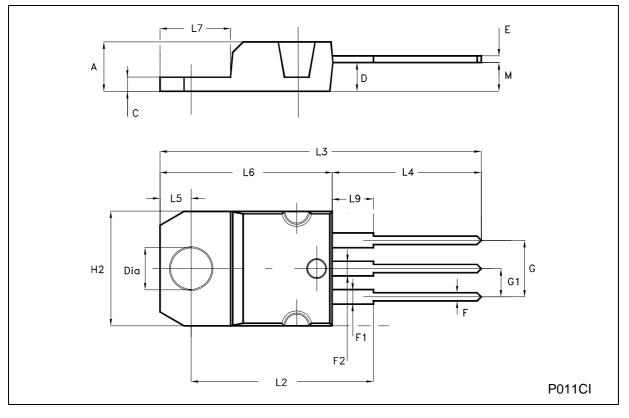
Resistive Load Switching Test Ciurcuit



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DIM.		mm			inch	
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.052
D	2.40		2.72	0.094		0.107
Е	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.202
G1	2.40		2.70	0.094		0.106
H2	10.00		10.40	0.394		0.409
L2		16.40			0.645	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.260
L9	3.50		3.93	0.137		0.154
М		2.60			0.102	





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